



SamHop Microelectronics Corp.

SDU/D3055L2

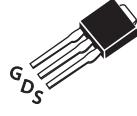
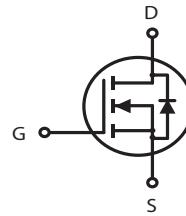
May,2004 ver1.1

N-Channel Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
V _{DSS}	I _D	R _{DSON} (mΩ) Max
20V	15A	60 @ V _{GS} = 4.5V
		70 @ V _{GS} = 2.5V

FEATURES

- Super high dense cell design for low R_{DSON}.
- Rugged and reliable.
- TO-252 and TO-251 Package.

SDU SERIES
TO-252AA(D-PAK)SDD SERIES
TO-251(I-PAK)

ABSOLUTE MAXIMUM RATINGS (T_A=25 °C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	20	V
Gate-Source Voltage	V _{GS}	±12	V
Drain Current-Continuous ^a @ T _J =125°C -Pulsed ^b (300ms Pulse Width)	I _D	15	A
	I _{DM}	25	A
Drain-Source Diode Forward Current ^a	I _S	15	A
Maximum Power Dissipation ^a	P _D	50	W
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 to 150	°C

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Case	R _{θJC}	3	°C/W
Thermal Resistance, Junction-to-Ambient	R _{θJA}	50	°C/W

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ELECTRICAL CHARACTERISTICS (TA = 25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ ^c	Max	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0V, I _D = 250µA	20			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 20V, V _{GS} = 0V		1		uA
Gate-Body Leakage	I _{GSS}	V _{GS} = ±8V, V _{DS} = 0V		±100		nA
ON CHARACTERISTICS^b						
Gate Threshold Voltage	V _{G(th)}	V _{DS} = V _{GS} , I _D = 250µA	0.7			V
Drain-Source On-State Resistance	R _{D(on)}	V _{GS} = 4.5V, I _D = 6.0A		34	60	m-ohm
		V _{GS} = 2.5V, I _D = 5.2A		45	70	m-ohm
On-State Drain Current	I _{D(on)}	V _{DS} = 5V, V _{GS} = 4.5V	20			A
Forward Transconductance	g _F	V _{DS} = 10V, I _D = 6.0A		17		S
DYNAMIC CHARACTERISTICS^c						
Input Capacitance	C _{ISS}	V _{DS} = 8V, V _{GS} = 0V f = 1.0MHz		705		pF
Output Capacitance	C _{OSS}			280		pF
Reverse Transfer Capacitance	C _{RSS}			65		pF
SWITCHING CHARACTERISTICS^c						
Turn-On Delay Time	t _{D(ON)}	V _{DD} = 10V, I _D = 1A, V _{GEN} = 4.5V, R _L = 10 ohm R _{GEN} = 6 ohm		10		ns
Rise Time	t _r			15		ns
Turn-Off Delay Time	t _{D(OFF)}			35		ns
Fall Time	t _f			20		ns
Total Gate Charge	Q _g	V _{DS} = 10V, I _D = 6A, V _{GS} = 10V		25		nC
		V _{DS} = 10V, I _D = 6A, V _{GS} = 4.5V		9.3		nC
Gate-Source Charge	Q _{gs}	V _{DS} = 10V, I _D = 6A, V _{GS} = 10V		2		nC
Gate-Drain Charge	Q _{gd}			2		nC

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ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise)

Parameter	Symbol	Condition	Min	Typ ^c	Max	Unit
DRAIN-SOURCE DIODE CHARACTERISTICS ^b						
Diode Forward Voltage	V_{SD}	$V_{GS} = 0V, I_S = 1.7A$		0.72	1.2	V

Notes

- a. Surface Mounted on FR4 Board, $t \leq 10\text{sec}$.
- b. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.
- c. Guaranteed by design, not subject to production testing.

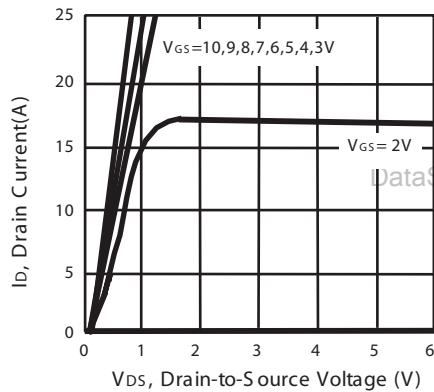


Figure 1. Output Characteristics

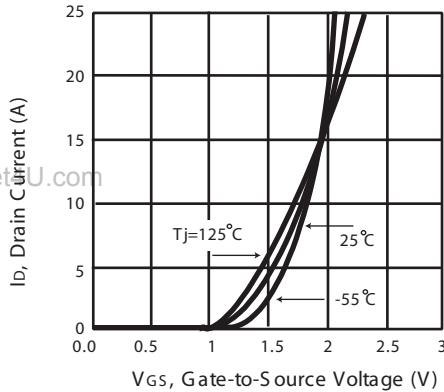


Figure 2. Transfer Characteristics

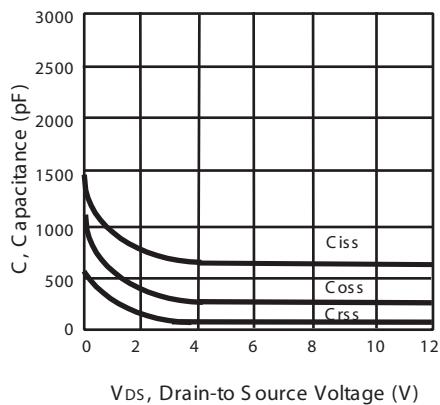


Figure 3. Capacitance

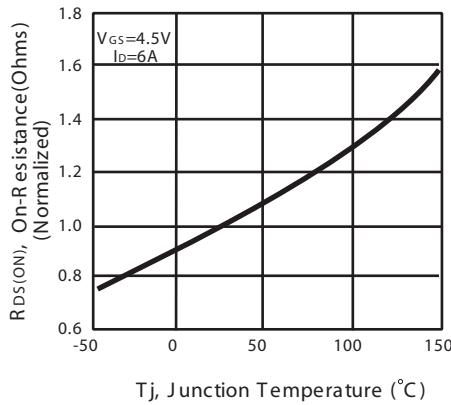
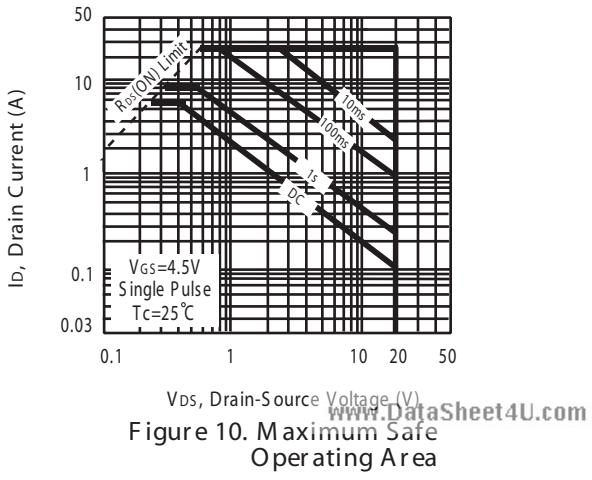
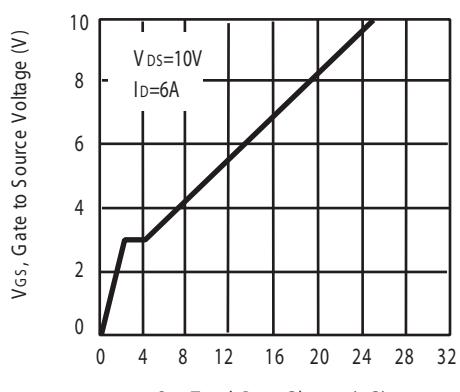
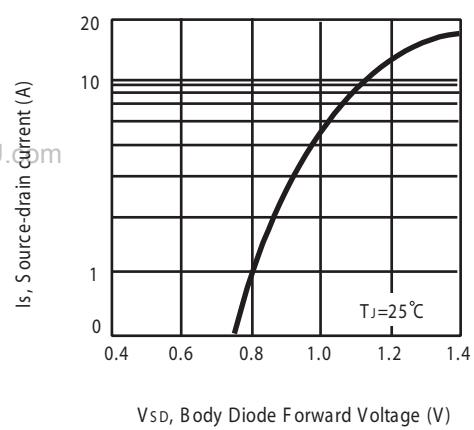
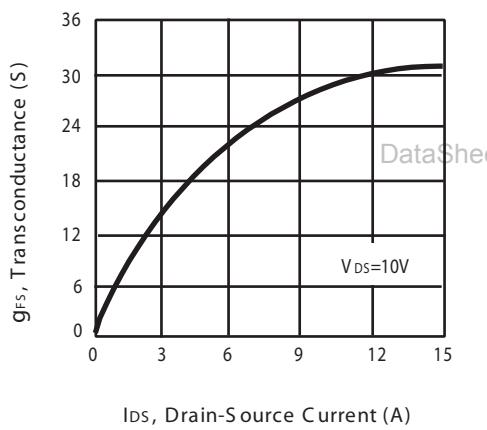
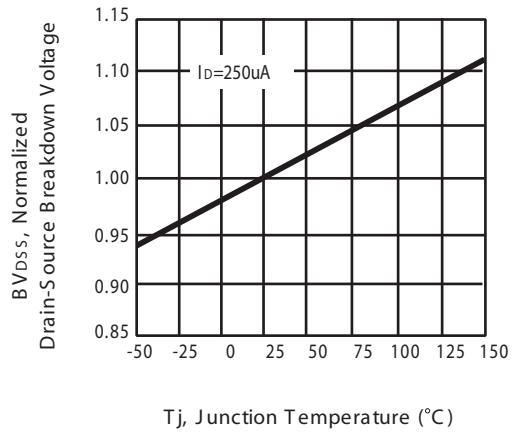
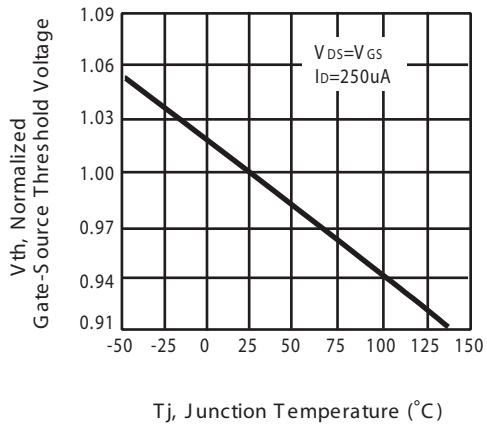


Figure 4. On-Resistance Variation with Temperature

S DU/D3055L2



S DU/D3055L2

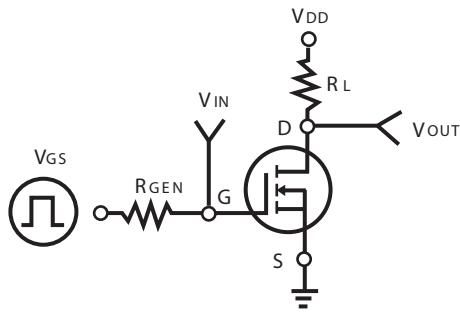


Figure 11. S switching Test Circuit

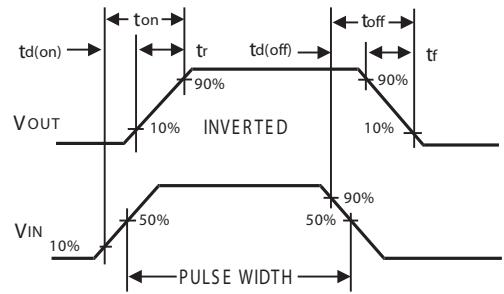


Figure 12. S switching Waveforms

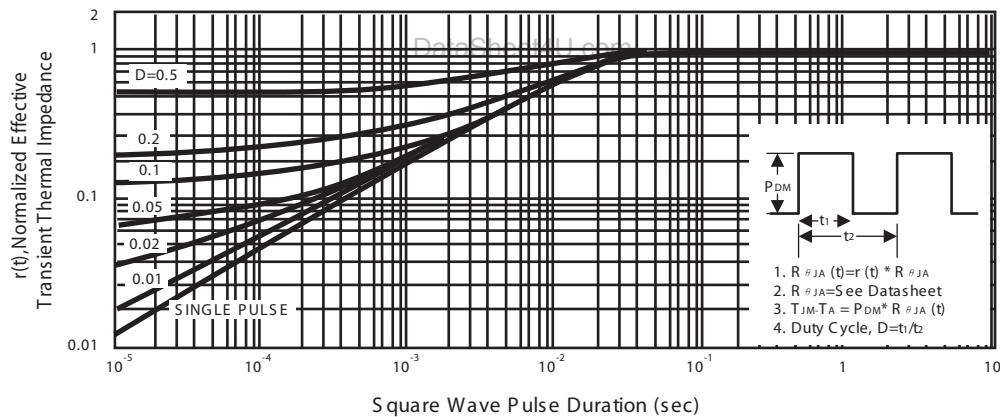
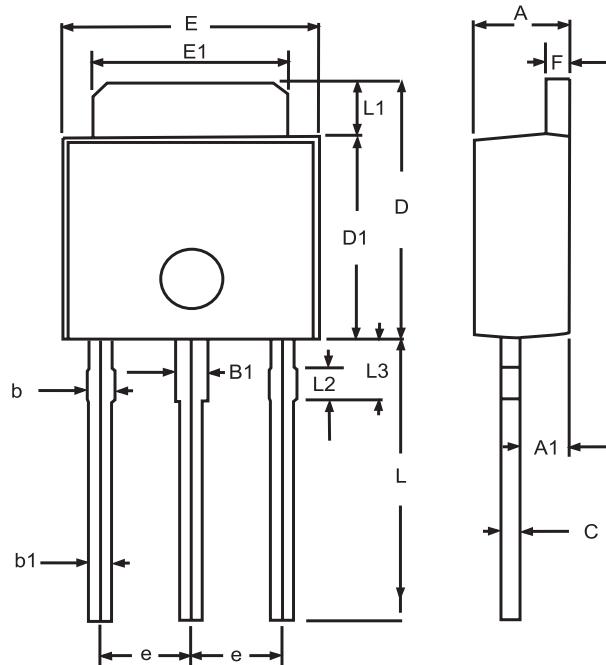


Figure 13. Normalized Thermal Transient Impedance Curve

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PACKAGE OUTLINE DIMENSIONS

TO-251

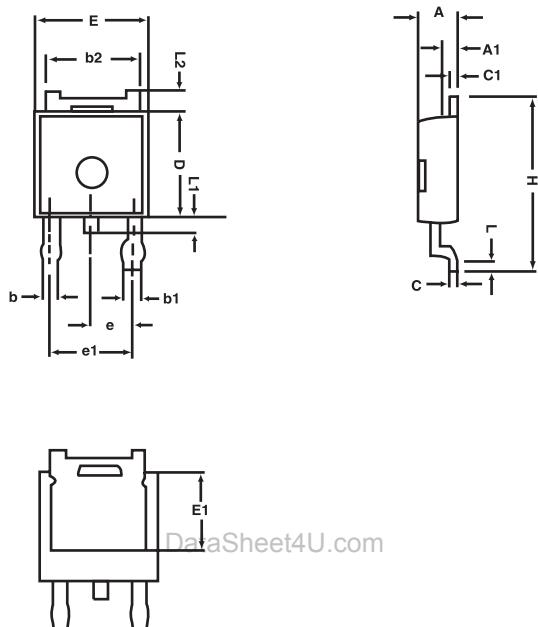


SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.20	2.40	0.087	0.095
A1	1.100	1.300	0.043	0.051
B1	0.650	1.050	0.026	0.041
b	0.500	0.900	0.020	0.035
b1	0.400	0.800	0.016	0.032
C	0.400	0.600	0.016	0.024
D	6.700	7.300	0.264	0.287
D1	5.400	5.650	0.213	0.222
E	6.40	6.650	0.252	0.262
e	2.100	2.500	0.083	0.098
F	0.400	0.600	0.016	0.024
L	7.000	8.000	0.276	0.315
L1	1.300	1.700	0.051	0.067
L2	0.700	0.900	0.028	0.035
L3	1.400	1.800	0.055	0.071

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PACKAGE OUTLINE DIMENSIONS

TO-252

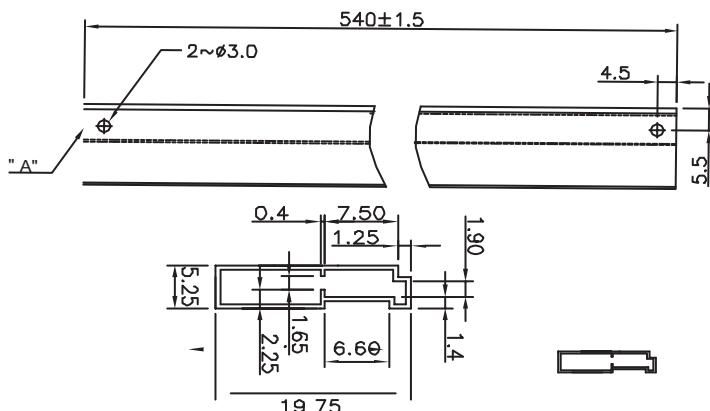


SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.25	2.35	0.089	0.093
A1	0.95	1.05	0.037	0.041
b	0.77	0.85	0.030	0.033
b1	0.84	0.94	0.033	0.037
b2	5.30	5.45	0.209	0.215
C	0.49	0.53	0.019	0.021
D	6.00	6.20	0.236	0.244
E	6.40	6.60	0.252	0.260
E1	3.18	3.67	0.125	0.145
e	2.29	BSC	0.090	BSC
H	9.70	10.10	0.382	0.398
L	1.425	1.625	0.056	0.064
L1	0.650	0.850	0.026	0.033
L2	0.600	REF.	0.024	REF.

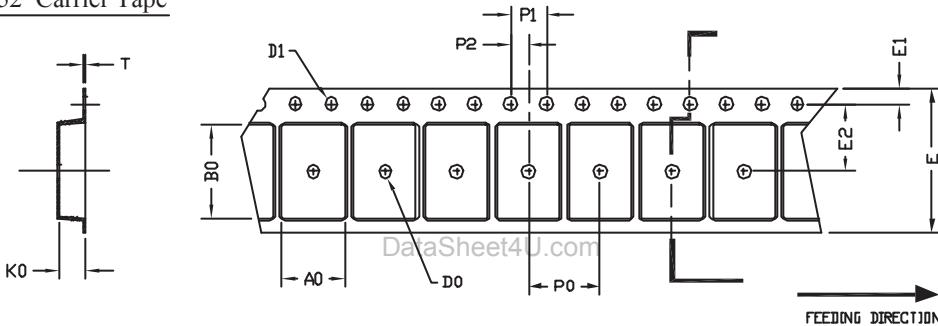
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TO251 Tube/TO-252 Tape and Reel Data

TO-251 Tube



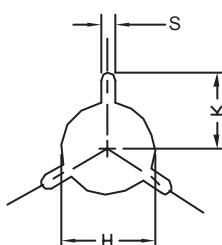
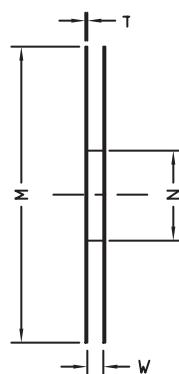
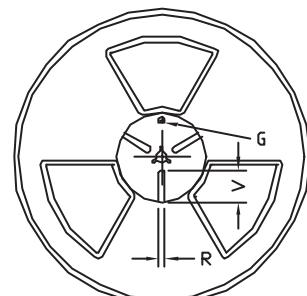
TO-252 Carrier Tape



UNIT:mm

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
TO-252 (16 mm)	6.80 ±0.1	10.3 ±0.1	2.50 ±0.1	ϕ 2	ϕ 1.5 + 0.1 - 0	16.0 0.3±	1.75 0.1±	7.5 ±0.15	8.0 ±0.1	4.0 ±0.1	2.0 ±0.15	0.3 ±0.05

TO-252 Reel



UNIT:mm

TAPE SIZE	REEL SIZE	M	N	W	T	H	K	S	G	R	V
16 mm	φ 330	φ 330 ± 0.5	φ 97 ± 1.0	17.0 + 1.5 - 0	2.2	φ 13.0 + 0.5 - 0.2	10.6	2.0 ± 0.5	---	---	---